# General purpose transistor (isolated transistor and diode)

# **EML4/UML4N**

2SC5585 and RB521S-30 are housed independently in a EMT5 or UMT5 package.

# Applications

DC / DC converter Motor driver

#### ●Features

1) Tr : Low Vce(sat) Di : Low VF

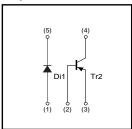
2) Small package

#### ●Structure

PNP Silicon epitaxial planar transistor Schottky barrier diode

The following characteristics apply to both Di1 and Tr2.

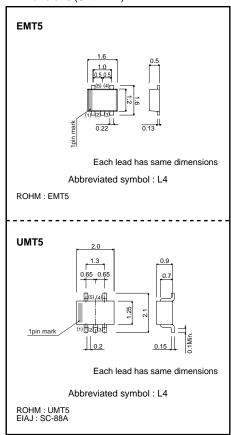
#### ●Equivalent circuit



#### Packaging specifications

| Туре                        | EML4 | UML4N |
|-----------------------------|------|-------|
| Package                     | EMT5 | UMT5  |
| Marking                     | L4   | L4    |
| Code                        | T2R  | TR    |
| Basic ordering unit(pieces) | 8000 | 3000  |

#### ●Dimensions (Unit: mm)



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# ● Absolute maximum ratings (Ta=25°C)

## Di1

| Parameter                             | Symbol | Limits | Unit |
|---------------------------------------|--------|--------|------|
| Average rectified forward current     | lo     | 200    | mA   |
| Forward current surge peak (60Hz, 1∞) | IFSM   | 1      | Α    |
| Reverse voltage (DC)                  | VR     | 30     | V    |
| Junction temperature                  | Tj     | 125    | °C   |

## Tr2

| Parameter                 | Symbol | Limits | Unit |
|---------------------------|--------|--------|------|
| Collector-base voltage    | Vсво   | -15    | V    |
| Collector-emitter voltage | Vceo   | -12    | V    |
| Emitter-base voltage      | Vево   | -6     | V    |
| Collector current         | lc     | -500   | mA   |
| Collector current         | Іср    | -1     | Α    |
| Power dissipation         | Pd     | 120    | mW * |
| Junction temperature      | Tj     | 150    | °C   |

<sup>\*</sup> Each terminal mounted on a recommended.

# Di1/DTr2

| Parameter           | Symbol | Limits      | Unit |
|---------------------|--------|-------------|------|
| Power dissipation   | Pd     | 150         | mW * |
| Storage temperature | Tstg   | -55 to +125 | °C   |

<sup>\*</sup> Each terminal mounted on a recommended.

# ●Electrical characteristics (Ta=25°C)

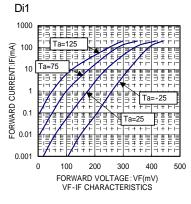
## Di1

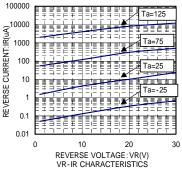
| Parameter       | Symbol | Min. | Тур. | Max. | Unit | Conditions            |
|-----------------|--------|------|------|------|------|-----------------------|
| Forward voltage | VF     | -    | 0.40 | 0.50 | V    | I <sub>F</sub> =200mA |
| Reverse current | IR     | -    | 4.0  | 30   | μΑ   | V <sub>R</sub> =10V   |

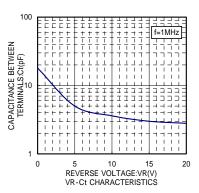
# Tr2

| Parameter                            | Symbol   | Min. | Тур. | Max. | Unit | Conditions                       |
|--------------------------------------|----------|------|------|------|------|----------------------------------|
| Collector-emitter breakdown voltage  | BVceo    | -12  | -    | -    | V    | Ic=-1mA                          |
| Collector-base breakdown voltage     | ВУсво    | -15  | -    | -    | V    | Ic=-10μA                         |
| Emitter-base breakdown voltage       | ВVево    | -6   | -    | -    | V    | Iε=-10μA                         |
| Collector cut-off current            | Ісво     | _    | -    | -100 | nA   | Vcb=-15V                         |
| Emitter cut-off current              | Ієво     | -    | -    | -100 | nA   | V <sub>EB</sub> =-6V             |
| Collector-emitter saturation voltage | VCE(sat) | _    | -100 | -250 | mV   | Ic=-200mA, I <sub>B</sub> =-10mA |
| DC current gain                      | hfe      | 270  | -    | 680  | -    | Vce=-2V, Ic=-10mA                |
| Transition frequency                 | f⊤       | _    | 260  | -    | MHz  | Vce=-2V, Ie=10mA, f=100MHz       |
| Collector output capacitance         | Cob      | _    | 6.5  | -    | pF   | Vcb=-10V, Ie=0mA, f=1MHz         |

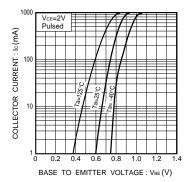
#### •Electrical characteristic curves

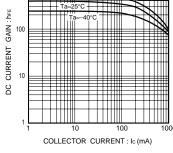






Tr2





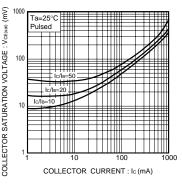
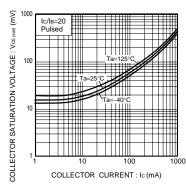
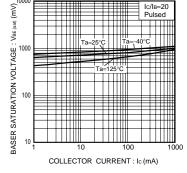


Fig.3 Grounded emitter propagation characteristics

Fig.4 DC current gain vs. collector current

Fig.5 Collector-emitter saturation voltage vs. collector current ( I )





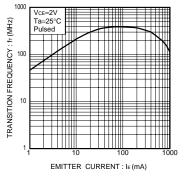
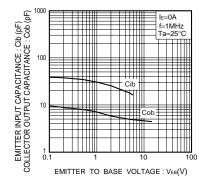


Fig.6 Collector-emitter saturation voltage vs. collector current ( II )

Fig.7 Base-emitter saturation voltage vs. collector current

Fig.8 Gain bandwidth product vs. emitter current



10 Ta=25°C Single Pulsed 100 ms ms 1

Fig.9 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

Fig.10 Safe operation area

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ROHM CO., LTD. 21 Saiin Mizosaki-cho, Ukyo-ku, Kyoto 615-8585, Japan

TEL:+81-75-311-2121 FAX:+81-75-315-0172



Appendix1-Rev2.0